

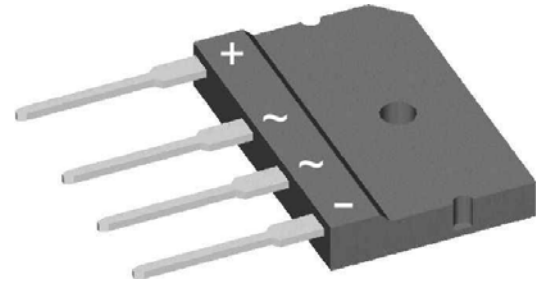
Standard Rectifier

1~ Rectifier	
V_{RRM}	= 1200 V
I_{DAV}	= 25 A
I_{FSM}	= 370 A

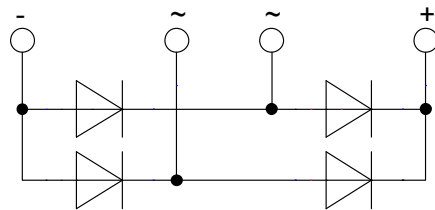
1~ Rectifier Bridge

Part number

GBO25-12NO1



Backside: isolated



Features / Advantages:

- Low forward voltage drop
- Planar passivated chips
- Easy to mount with one screw
- Space and weight savings

Applications:

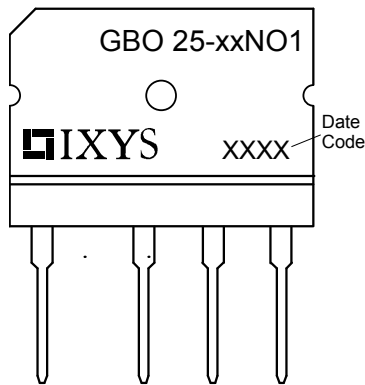
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Package: GBFP

- Isolation Voltage: 2500V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Soldering pins for PCB mounting
- Base plate: Plastic overmolded tab
- Reduced weight

Rectifier				Ratings		
Symbol	Definition	Conditions	min.	typ.	max.	Unit
V_{RSM}	max. non-repetitive reverse blocking voltage	$T_{VJ} = 25^{\circ}C$			1300	V
V_{RRM}	max. repetitive reverse blocking voltage	$T_{VJ} = 25^{\circ}C$			1200	V
I_R	reverse current	$V_R = 1200 V$	$T_{VJ} = 25^{\circ}C$		40	μA
		$V_R = 1200 V$	$T_{VJ} = 150^{\circ}C$		1.5	mA
V_F	forward voltage drop	$I_F = 10 A$	$T_{VJ} = 25^{\circ}C$		1.06	V
					1.17	V
		$I_F = 20 A$	$T_{VJ} = 150^{\circ}C$		0.92	V
					1.09	V
I_{DAV}	bridge output current	$T_C = 105^{\circ}C$ rectangular $d = 0.5$	$T_{VJ} = 175^{\circ}C$		25	A
V_{FO}	threshold voltage		$T_{VJ} = 175^{\circ}C$		0.74	V
r_F	slope resistance				16.3	m Ω
R_{thJC}	thermal resistance junction to case				4.3	K/W
R_{thCH}	thermal resistance case to heatsink			0.50		K/W
P_{tot}	total power dissipation		$T_C = 25^{\circ}C$		35	W
I_{FSM}	max. forward surge current	$t = 10 \text{ ms; (50 Hz), sine}$ $t = 8,3 \text{ ms; (60 Hz), sine}$	$T_{VJ} = 45^{\circ}C$ $V_R = 0 V$		370	A
					400	A
		$t = 10 \text{ ms; (50 Hz), sine}$ $t = 8,3 \text{ ms; (60 Hz), sine}$	$T_{VJ} = 150^{\circ}C$ $V_R = 0 V$		315	A
					340	A
I^2t	value for fusing	$t = 10 \text{ ms; (50 Hz), sine}$ $t = 8,3 \text{ ms; (60 Hz), sine}$	$T_{VJ} = 45^{\circ}C$ $V_R = 0 V$		685	A ² s
					665	A ² s
		$t = 10 \text{ ms; (50 Hz), sine}$ $t = 8,3 \text{ ms; (60 Hz), sine}$	$T_{VJ} = 150^{\circ}C$ $V_R = 0 V$		495	A ² s
					480	A ² s
C_J	junction capacitance	$V_R = 400 V; f = 1 \text{ MHz}$	$T_{VJ} = 25^{\circ}C$		10	pF

Package GBFP		Ratings				
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal			70	A
T_{stg}	storage temperature		-55		150	°C
T_{VJ}	virtual junction temperature		-40		175	°C
Weight				7		g
M_D	mounting torque		0.5		0.8	Nm
F_C	mounting force with clip		20		120	N
$d_{Spp/App}$	creepage distance on surface striking distance through air	terminal to terminal	4.9			mm
$d_{Spb/Appb}$		terminal to backside	2.5			mm
V_{ISOL}	isolation voltage	t = 1 second	2500			V
		t = 1 minute	2080			V
		50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA				
R_{thJA}	thermal resistance junction to ambient			50		K/W



Ordering	Part Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	GBO25-12NO1	GBO25-12NO1	Tube	16	500233

Equivalent Circuits for Simulation

* on die level

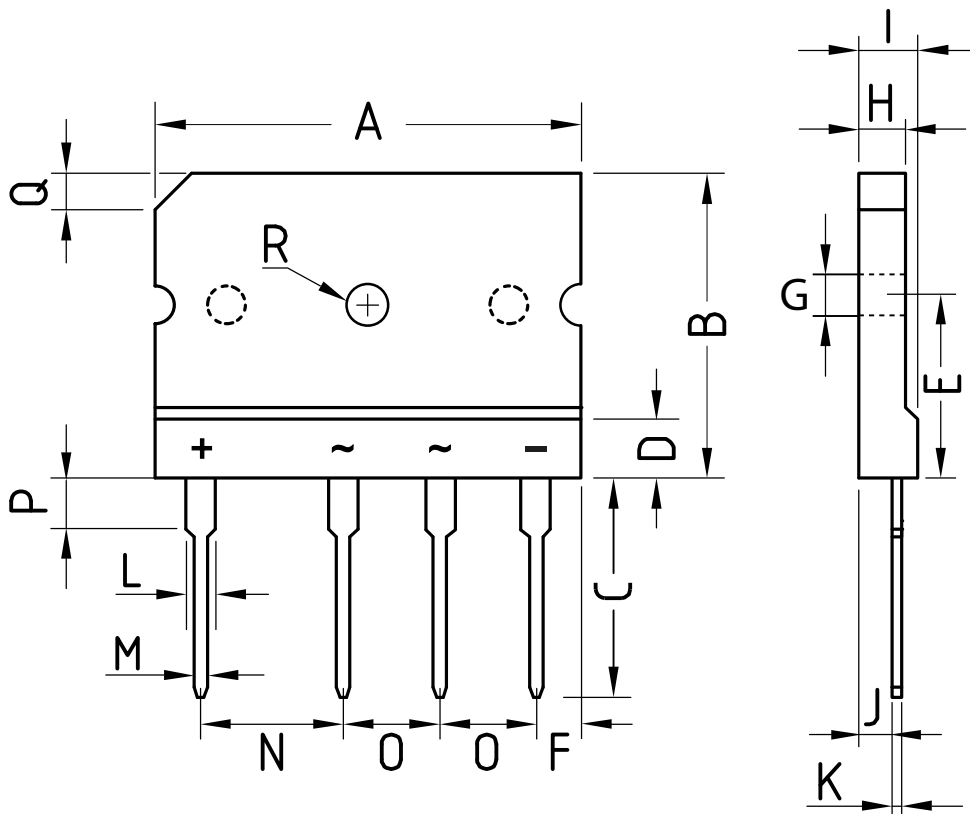
$T_{VJ} = 175^\circ\text{C}$



Rectifier

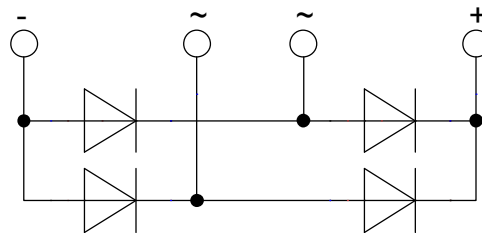
$V_{0\max}$	threshold voltage	0.74	V
$R_{0\max}$	slope resistance *	13.7	mΩ

Outlines GBFP



DIM.	MIN.	MAX.
A	29.7	30.3
B	19.7	20.3
C	17.0	18.0
D	4.7	4.9
E	10.8	11.2
F	2.3	2.7
G	3.1	3.4
H	3.4	3.8
I	4.4	4.8
J	2.5	2.9
K	0.6	0.8
L	2.0	2.4
M	0.9	1.1
N	9.8	10.2
O	7.3	7.7
P	3.8	4.2
Q	(3.0) x 45°	
R (Ø)	3.1	3.4

All Dimensions in millimeter



Rectifier

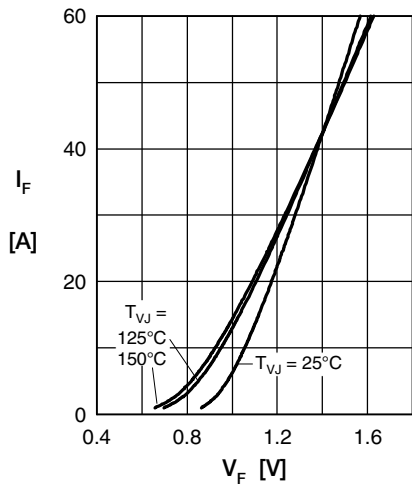


Fig. 1 Forward current vs. voltage drop per diode

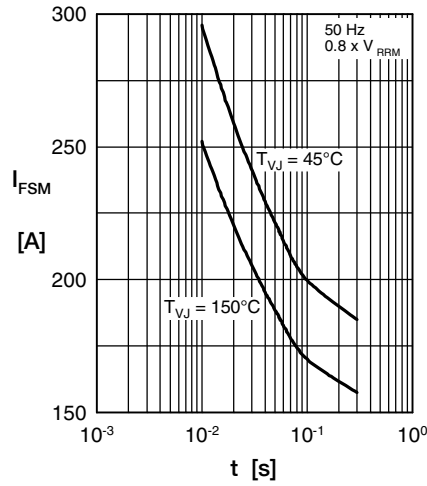


Fig. 2 Surge overload current vs. time per diode

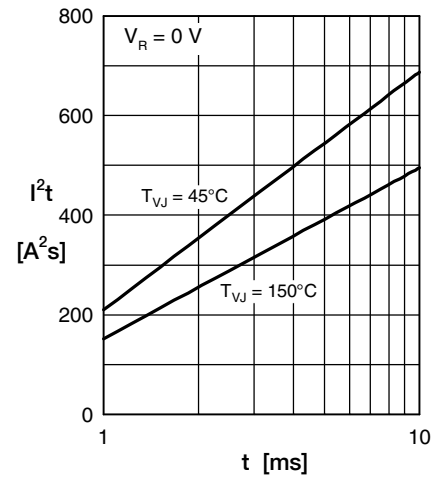


Fig. 3 I^2t vs. time per diode

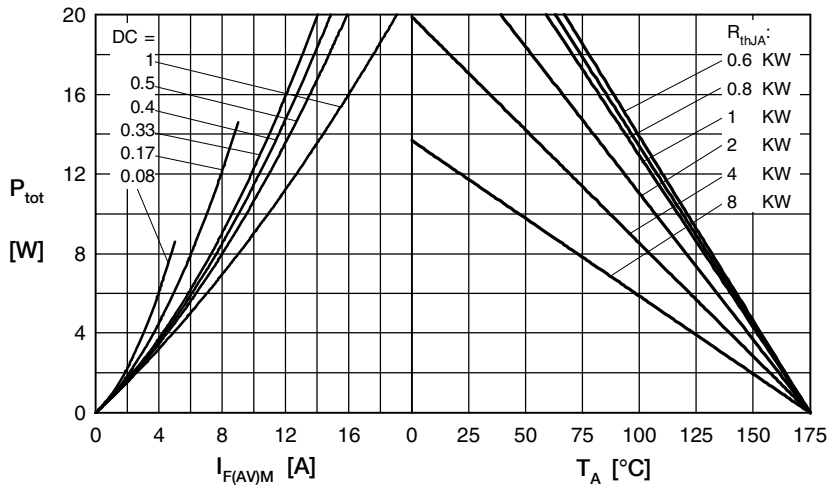


Fig. 4 Power dissipation vs. forward current and ambient temperature per diode

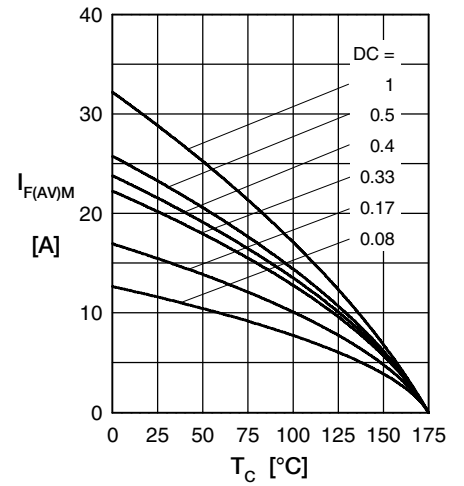


Fig. 5 Max. forward current vs. case temperature per diode

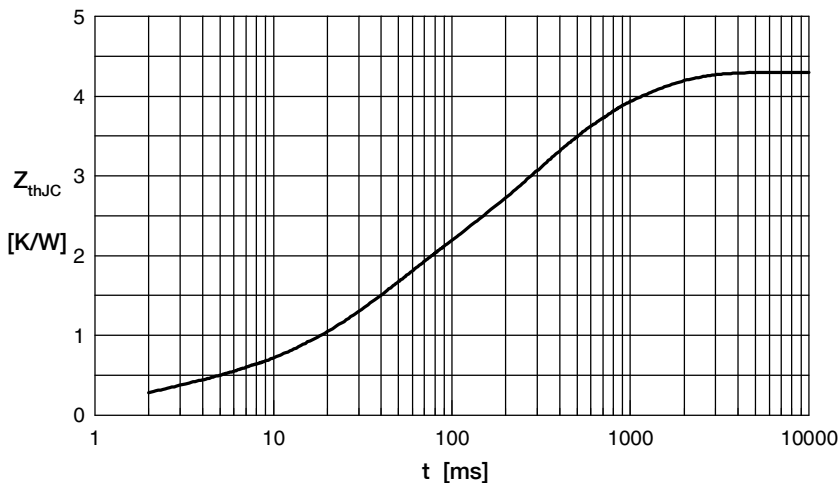


Fig. 6 Transient thermal impedance junction to case vs. time per diode

Constants for Z_{thJC} calculation:

i	R_{th} (K/W)	t_i (s)
1	0.302	0.002
2	1.252	0.032
3	1.582	0.227
4	1.164	0.820

Mouser Electronics

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